

# mos integrated circuit $\mu PD78P083$

## 8-BIT SINGLE-CHIP MICROCONTROLLER

#### **DESCRIPTION**

The  $\mu$ PD78P083 is a member of the  $\mu$ PD78083 subseries of the 78K/0 series products. It includes an on-chip, 24-Kbyte, one-time PROM or EPROM.

Because this device can be programmed by users, it is ideally suited for applications involving the evaluation of systems in development stages, small-scale production of many different products, and rapid development and time-to-market of a new product.

Caution The μPD78P083DU does not maintain planned reliability when used in your systems' mass-produced products. Please use only experimentally or for evaluation purposes during trial manufacture.

The details of functions are described in the user's manuals. Be sure to read the following manuals before designing.

μPD78083 Subseries User's Manual : IEU-1407 78K/0 Series User's Manual — Instructions : IEU-1372

#### **FEATURES**

- Pin-compatible with mask ROM version (except VPP pin)
- Internal PROM: 24 Kbytes Note
  - μPD78P083DU: Reprogrammable (ideally suited for system evaluation)
  - μPD78P083CU, μPD78P083GB: One-time programmable (ideally suited for small-scale production)
- Internal high-speed RAM: 512 bytes Note
- Can be operated in the same supply voltage as the mask ROM version (VDD = 1.8 to 5.5 V)
- Corresponding to QTOP<sup>™</sup> Microcontrollers

**Note** The internal PROM and internal high-speed RAM capacities can be changed by setting the internal memory size switching register (IMS).

**Remark** QTOP microcontroller is a general term for microcontrollers which incorporate one-time PROM and are totally supported by NEC's programming service (from programming to marking, screening and verification).

#### Differs from the mask ROM version in the following points

The same memory mapping as the mask ROM version is enabled by setting the internal memory size switching register (IMS).

In this document, the term PROM is used in parts common to one-time PROM versions and EPROM versions.

The information in this document is subject to change without notice.

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## **ORDERING INFORMATION**

| Part Number         | Package                             | Internal ROM  |  |
|---------------------|-------------------------------------|---------------|--|
| μPD78P083CU         | 42-pin plastic shrink DIP (600 mil) | One-Time PROM |  |
| μPD78P083GB-3B4     | 44-pin plastic QFP (10 x 10 mm)     | One-Time PROM |  |
| μPD78P083GB-3BS-MTX | 44-pin plastic QFP (10 x 10 mm)     | One-Time PROM |  |
| μPD78P083DU         | 42-pin ceramic shrink DIP           | EPROM         |  |
|                     | (with window) (600 mil)             |               |  |

Caution  $\mu$ PD78P083GB has two kinds of package. (Refer to 9. PACKAGE DRAWINGS). Please refer an NEC's sales representative for the available package.

## **QUALITY GRADE**

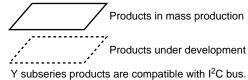
| Part Number         | Package                             | Quality Grades |  |
|---------------------|-------------------------------------|----------------|--|
| μPD78P083CU         | 42-pin plastic shrink DIP (600 mil) | Standard       |  |
| μPD78P083GB-3B4     | 44-pin plastic QFP (10 x 10 mm)     | Standard       |  |
| μPD78P083GB-3BS-MTX | 44-pin plastic QFP (10 x 10 mm)     | Standard       |  |
| μPD78P083DU         | 42-pin ceramic shrink DIP           | Not applicable |  |
|                     | (with window) (600 mil)             |                |  |

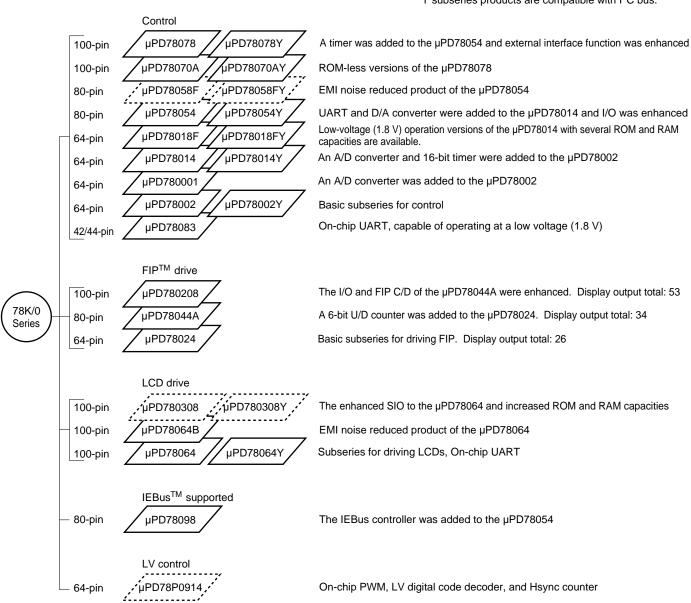
Please refer to "Quality grades on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.



#### 78K/0 SERIES DEVELOPMENT

The following shows the 78K/0 series products development. Subseries names are shown inside frames.







The following table shows the differences among subseries functions.

|             | Function   | ROM          | Timer |        |       |     | 8-bit | 8-bit | Serial Interface | I/O | V <sub>DD</sub> MIN. | External  |
|-------------|------------|--------------|-------|--------|-------|-----|-------|-------|------------------|-----|----------------------|-----------|
| Part Number |            | Capacity     | 8-bit | 16-bit | Watch | WDT | A/D   | D/A   |                  |     | Value                | Expansion |
| Control     | μPD78078   | 32 K to 60 K | 4ch   | 1ch    | 1ch   | 1ch | 8ch   | 2ch   | 3ch (UART: 1ch)  | 88  | 1.8 V                | Available |
|             | μPD78070A  | -            |       |        |       |     |       |       |                  | 61  | 2.7 V                |           |
|             | μPD78058F  | 48 K to 60 K | 2ch   |        |       |     |       |       |                  | 69  |                      |           |
|             | μPD78054   | 16 K to 60 K |       |        |       |     |       |       |                  |     | 2.0 V                |           |
|             | μPD78018F  | 8 K to 60 K  |       |        |       |     |       | _     | 2ch              | 53  | 1.8 V                |           |
|             | μPD78014   | 8 K to 32 K  |       |        |       |     |       |       |                  |     | 2.7 V                |           |
|             | μPD780001  | 8 K          |       | _      | _     |     |       |       | 1ch              | 39  |                      | -         |
|             | μPD78002   | 8 K to 16 K  |       |        | 1ch   |     | _     |       |                  | 53  |                      | Available |
|             | μPD78083   |              |       |        | _     |     | 8ch   |       | 1ch (UART: 1ch)  | 33  | 1.8 V                | -         |
| FIP drive   | μPD780208  | 32 K to 60 K | 2ch   | 1ch    | 1ch   | 1ch | 8ch   | -     | 2ch              | 74  | 2.7 V                | -         |
|             | μPD78044A  | 16 K to 40 K |       |        |       |     |       |       |                  | 68  |                      |           |
|             | μPD78024   | 24 K to 32 K |       |        |       |     |       |       |                  | 54  |                      |           |
| LCD drive   | μPD780308  | 48 K to 60 K | 2ch   | 1ch    | 1ch   | 1ch | 8ch   | -     | 3ch (UART: 1ch)  | 57  | 1.8 V                | -         |
|             | μPD78064B  | 32 K         |       |        |       |     |       |       | 2ch (UART: 1ch)  |     | 2.0 V                |           |
|             | μΡD78064   | 16 K to 32 K |       |        |       |     |       |       |                  |     |                      |           |
| IEBus       | μPD78098   | 32 K to 60 K | 2ch   | 1ch    | 1ch   | 1ch | 8ch   | 2ch   | 3ch (UART: 1ch)  | 69  | 2.7 V                | Available |
| supported   |            |              |       |        |       |     |       |       |                  |     |                      |           |
| LV control  | μPD78P0914 | 32 K         | 6ch   | -      | -     | 1ch | 8ch   | -     | 2ch              | 54  | 4.5 V                | Available |



## **FUNCTION DESCRIPTION**

| Item                 |                        | Function   |  |  |  |
|----------------------|------------------------|--|--|--|--|
| Internal memory      |                        | PROM: 24 Kbytes Note   |  |  |  |
|                      |                        | • RAM  |  |  |  |
|                      |                        | Internal high-speed RAM: 512 bytes Note  |  |  |  |
| Memory space         |                        | 64 Kbytes  |  |  |  |
| General register     |                        | 8 bits x 32 registers (8 bits x 8 registers x 4 banks)                                 |  |  |  |
| Instruction cycles   |                        | Instruction execution time variable function is integrated.                            |  |  |  |
|                      |                        | 0.4 μs/0.8 μs/1.6 μs/3.2 μs/6.4 μs/12.8 μs (@5.0-MHz operation with main system clock) |  |  |  |
| Instruction set      |                        | 16-bit operation   |  |  |  |
|                      |                        | Multiply/divide (8 bits x 8 bits, 16 bits ÷ 8 bits)                                    |  |  |  |
|                      |                        | Bit manipulation (set, reset, test, Boolean operation)                                 |  |  |  |
|                      |                        | BCD adjust, etc.   |  |  |  |
| I/O ports            |                        | Total : 33   |  |  |  |
|                      |                        | CMOS input : 1   |  |  |  |
|                      |                        | CMOS input/output : 32   |  |  |  |
| A/D converter        |                        | 8-bit resolution x 8 channels  |  |  |  |
| Serial interface     |                        | 3-wire serial I/O/UART mode selectable: 1 channel                                      |  |  |  |
| Timer                |                        | 8-bit timer/event counter: 2 channels  |  |  |  |
|                      |                        | Watchdog timer: 1 channel  |  |  |  |
| Timer output         |                        | 2 pins (8-bit PWM output enable)   |  |  |  |
| Clock output         |                        | 19.5 kHz, 39.1 kHz, 78.1 kHz, 156 kHz, 313 kHz, 625 kHz, 1.25 MHz, 2.5 MHz, and        |  |  |  |
|                      |                        | 5.0 MHz (@ 5.0-MHz operation with main system clock)                                   |  |  |  |
| Buzzer output        |                        | 1.2 kHz, 2.4 kHz, 4.9 kHz, and 9.8 kHz   |  |  |  |
|                      |                        | (@ 5.0-MHz operation with main system clock)   |  |  |  |
| Vectored             | Maskable interrupts    | Internal : 8 external : 3  |  |  |  |
| interrupts           | Non-maskable interrupt | Internal : 1   |  |  |  |
|                      | Software interrupt     | Internal : 1   |  |  |  |
| Power supply voltage |                        | V <sub>DD</sub> = 1.8 to 5.5 V   |  |  |  |
| Operating ambien     | t temperature          | $T_A = -40 \text{ to } +85^{\circ}\text{C}$  |  |  |  |
| Packages             |                        | 42-pin plastic shrink DIP (600 mil)  |  |  |  |
|                      |                        | • 44-pin plastic QFP (10 x 10 mm)  |  |  |  |
|                      |                        | 42-pin ceramic shrink DIP (with window) (600 mil)                                      |  |  |  |
|                      |                        |  |  |  |  |

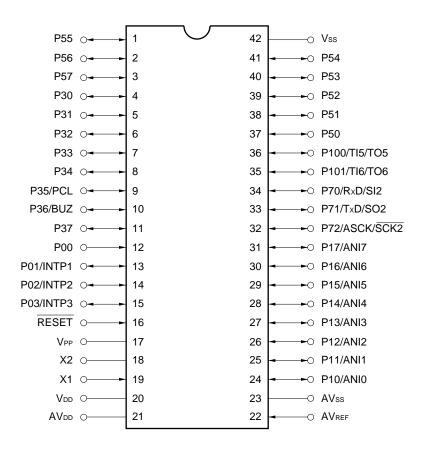
**Note** Internal PROM and high-speed RAM capacities can be changed by setting the internal memory size switching register (IMS).



## PIN CONFIGURATIONS (Top View)

### (1) Normal operating mode

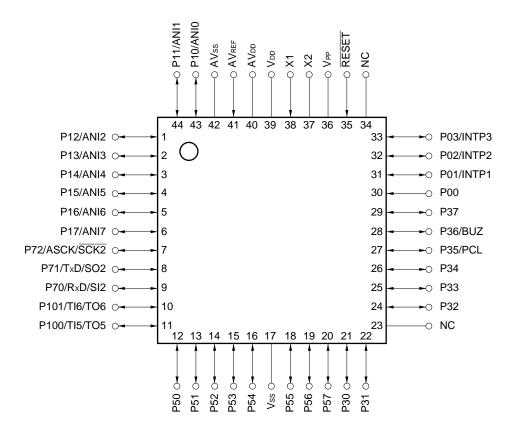
- 42-pin plastic shrink DIP (600 mil) μPD78P083CU
- 42-pin ceramic shrink DIP (with window) (600 mil) μPD78P083DU



- Cautions 1. Connect VPP pin directly to Vss.
  - Connect AVDD pin to VDD.
  - 3. Connect AVss pin to Vss.



• 44-pin plastic QFP (10 x 10 mm)  $\mu$ PD78P083GB-3B4,  $\mu$ PD78P083GB-3BS-MTX



- Cautions 1. Connect VPP pin directly to Vss.
  - Connect AVDD pin to VDD.
  - 3. Connect AVss pin to Vss.
  - Connect NC pin to Vss for noise protection (It can be left open).



P00 to P03 : Port 0
P10 to P17 : Port 1
P30 to P37 : Port 3
P50 to P57 : Port 5
P70 to P72 : Port 7
P100, P101 : Port 10

INTP1 to INTP3 : Interrupt from Peripherals

TI5, TI6 : Timer Input
TO5, TO6 : Timer Output
SI2 : Serial Input
SO2 : Serial Output

SCK2: Serial ClockRxD: Receive DataTxD: Transmit Data

ASCK : Asynchronous Serial Clock

PCL : Programmable Clock

BUZ : Buzzer Clock

X1, X2 : Crystal (Main System Clock)

RESET : Reset

ANI0-ANI7 : Analog Input

AVDD : Analog Power Supply

AVss : Analog Ground

AVREF : Analog Reference Voltage

V<sub>DD</sub> : Power Supply

VPP : Programming Power Supply

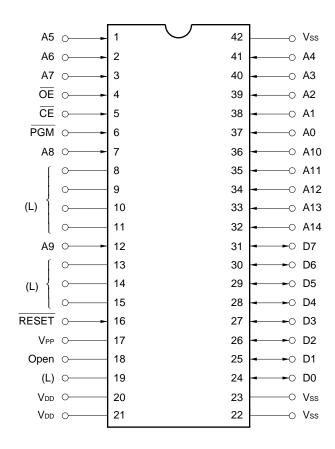
Vss : Ground

NC : Non-connection



## (2) PROM programming mode

- 42-pin plastic shrink DIP (600 mil) μPD78P083CU
- 42-pin ceramic shrink DIP (with window) (600 mil) μPD78P083DU

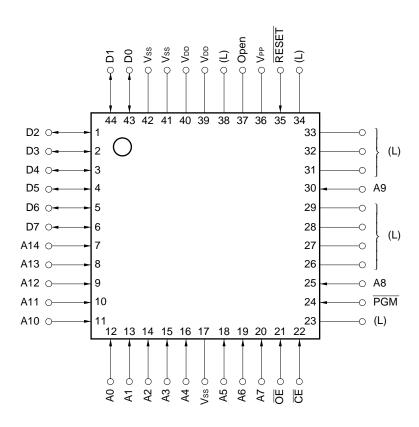


Cautions 1. (L): Individually connect to Vss via a pull-down resistor.

Vss: Connect to GND.
 RESET: Set to low level.
 Open: Leave open.



44-pin plastic QFP (10 x 10 mm)
 μPD78P083GB-3B4, μPD78P083GB-3BS-MTX



Cautions 1. (L): Individually connect to Vss via a pull-down resistor.

Vss: Connect to GND.
 RESET: Set to low level.
 Open: Leave open.

A0 to A14 : Address Bus RESET : Reset

D0 to D7 : Data Bus VDD : Power Supply

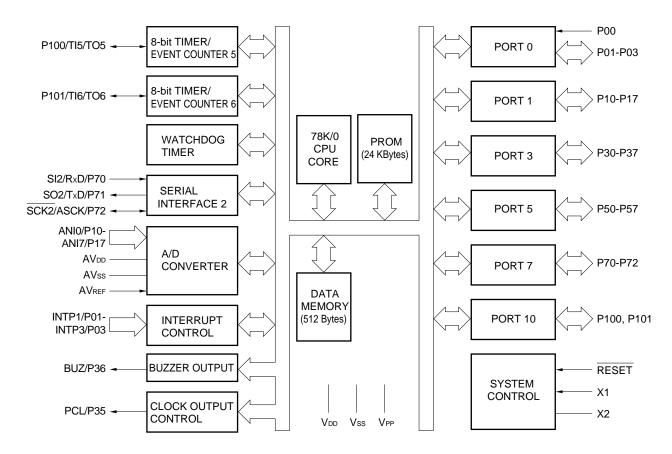
CE : Chip Enable VPP : Programming Power Supply

OE : Output Enable Vss : Ground

PGM : Program



#### **BLOCK DIAGRAM**





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## 1. DIFFERENCES BETWEEN THE $\mu$ PD78P083 AND MASK ROM VERSIONS

The µPD78P083 is a single-chip microcontroller with an on-chip one-time PROM or with an on-chip EPROM which has program write, erasure and rewrite capability.

Setting the internal memory size switching register (IMS) makes the functions except the PROM specification identical to the mask ROM versions, that is, the  $\mu$ PD78081 and  $\mu$ PD78082.

Differences between the  $\mu PD78P083$  and mask ROM versions are shown in Table 1-1.

Table 1-1. Differences between the  $\mu$ PD78P083 and Mask ROM Versions

| Parameter                            | μPD78P083                             | Mask ROM Versions    |
|--------------------------------------|---------------------------------------|----------------------|
| ROM type                             | One-time PROM/EPROM                   | Mask ROM             |
| ROM capacity                         | 24 Kbytes                             | μPD78081 : 8 Kbytes  |
|                                      |                                       | μPD78082 : 16 Kbytes |
| Internal high-speed RAM capacity     | 512 bytes                             | μPD78081 : 256 bytes |
|                                      |                                       | μPD78082 : 384 bytes |
| Internal ROM and internal high-speed | Can be changed Note                   | Can not be changed   |
| RAM capacity change by internal      |                                       |                      |
| memory size switching register       |                                       |                      |
| IC pin                               | No                                    | Yes                  |
| V <sub>PP</sub> pin                  | Yes                                   | No                   |
| Electrical specifications            | Refer to a data sheet of each product |                      |

**Note** The internal PROM becomes 24 Kbytes and the internal expansion RAM becomes 512 bytes by the RESET input.



## 2. PIN FUNCTIONS

## 2.1 Pins in Normal Operating Mode

## (1) Port pins

| Pin Name | Input/Output | 1                         | Function                          | After Reset | Alternate Function |
|----------|--------------|---------------------------|-----------------------------------|-------------|--------------------|
| P00      | Input        | Port 0                    | Input only                        | Input       | _                  |
| P01      | Input/output | 4-bit input/output port   | Input/output is specifiable       | Input       | INTP1              |
| P02      |              |                           | bit-wise. When used as the        |             | INTP2              |
| P03      |              |                           | input port, it is possible to     |             | INTP3              |
|          |              |                           | connect a pull-up resistor by     |             |                    |
|          |              |                           | software.                         |             |                    |
| P10-P17  | Input/output | Port 1                    |                                   | Input       | ANI0-ANI7          |
|          |              | 8-bit input/output port   |                                   |             |                    |
|          |              | Input/output is specifiab | le bit-wise.                      |             |                    |
|          |              | When used as the inpu     | t port, it is possible to connect |             |                    |
|          |              | a pull-up resistor by sof | tware. Note                       |             |                    |
| P30-P34  | Input/output | Port 3                    |                                   | Input       | _                  |
| P35      |              | 8-bit input/output port   |                                   |             | PCL                |
| P36      |              | Input/output is specifiab | le bit-wise.                      |             | BUZ                |
| P37      |              | When used as the inpu     | t port, it is possible to connect |             | _                  |
|          |              | a pull-up resistor by sof | tware.                            |             |                    |
| P50-P57  | Input/output | Port 5                    |                                   | Input       | _                  |
|          |              | 8-bit input/output port   |                                   |             |                    |
|          |              | Can drive up to seven L   | .EDs directly.                    |             |                    |
|          |              | Input/output is specifiab | le bit-wise.                      |             |                    |
|          |              | When used as the inpu     | t port, it is possible to connect |             |                    |
|          |              | a pull-up resistor by sof | tware.                            |             |                    |
| P70      | Input/output | Port 7                    |                                   | Input       | SI2/RxD            |
| P71      |              | 3-bit input/output port   |                                   |             | SO2/TxD            |
| P72      |              | Input/output is specifiab | le bit-wise.                      |             | SCK2/ASCK          |
|          |              | When used as the inpu     | t port, it is possible to connect |             |                    |
|          |              | a pull-up resistor by sof | tware.                            |             |                    |
| P100     | Input/output | Port 10                   | Port 10                           |             | TI5/TO5            |
| P101     |              | 2-bit input/output port   |                                   |             | TI6/TO6            |
|          |              | Input/output is specifiab | le bit-wise.                      |             |                    |
|          |              | When used as the inpu     | t port, it is possible to connect |             |                    |
|          |              | a pull-up resistor by sof | tware.                            |             |                    |

**Note** When P10/ANI0-P17/ANI7 pins are used as the analog inputs for the A/D converter, set the port 1 to the input mode. The on-chip pull-up resistor is automatically disabled.



## (2) Non-port pins

| Pin Name        | Input/Output | Function  | After Reset | Alternate Function |
|-----------------|--------------|---|-------------|--------------------|
| INTP1           | Input        | External interrupt input by which the active edge (rising edge,   | Input       | P01                |
| INTP2           |              | falling edge, or both rising and falling edges) can be specified. |             | P02                |
| INTP3           |              |   |             | P03                |
| SI2             | Input        | Serial interface serial data input.                               | Input       | P70/RxD            |
| SO2             | Output       | Serial interface serial data output.                              | Input       | P71/TxD            |
| SCK2            | Input/Output | Serial interface serial clock input/output.                       | Input       | P72/ASCK           |
| RxD             | Input        | Asynchronous serial interface serial data input.                  | Input       | P70/SI2            |
| TxD             | Output       | Asynchronous serial interface serial data output.                 | Input       | P71/SO2            |
| ASCK            | Input        | Asynchronous serial interface serial clock input.                 | Input       | P72/SCK2           |
| TI5             | Input        | External count clock input to 8-bit timer (TM5).                  | Input       | P100/TO5           |
| TI6             |              | External count clock input to 8-bit timer (TM6).                  |             | P101/TO6           |
| TO5             | Output       | 8-bit timer output.   | Input       | P100/TI5           |
| TO6             |              |   |             | P101/TI6           |
| PCL             | Output       | Clock output. (for main system clock trimming)                    | Input       | P35                |
| BUZ             | Output       | Buzzer output.  | Input       | P36                |
| ANI0-ANI7       | Input        | A/D converter analog input.                                       | Input       | P10-P17            |
| AVREF           | Input        | A/D converter reference voltage input.                            | _           | _                  |
| AVDD            | _            | A/D converter analog power supply. Connected to VDD.              | _           | _                  |
| AVss            | _            | A/D converter ground potential. Connected to Vss.                 | -           | _                  |
| RESET           | Input        | System reset input.   | -           | _                  |
| X1              | Input        | Main system clock oscillation crystal connection.                 | -           | _                  |
| X2              | _            |   | -           | _                  |
| V <sub>DD</sub> | -            | Positive power supply.  | _           | _                  |
| V <sub>PP</sub> | _            | High-voltage applied during program write/verification.           | _           | _                  |
|                 |              | Connected directly to Vss in normal operating mode.               |             |                    |
| Vss             | _            | Ground potential.   | -           | _                  |
| NC              | _            | Does not internally connected. Connect to Vss.                    | _           | _                  |
|                 |              | (It can be left open)   |             |                    |



## 2.2 Pins in PROM Programming Mode

| Pin Name        | Input/Output | Function   |
|-----------------|--------------|--|
| RESET           | Input        | PROM programming mode setting  |
|                 |              | When +5 V or +12.5 V is applied to the VPP pin and a low-level signal is applied to the RESET pin, |
|                 |              | this chip is set in the PROM programming mode.   |
| VPP             | Input        | PROM programming mode setting and high-voltage applied during program write/verification.          |
| A0-A14          | Input        | Address bus  |
| D0-D7           | Input/output | Data bus   |
| CE              | Input        | PROM enable input/program pulse input  |
| ŌĒ              | Input        | Read strobe input to PROM  |
| PGM             | Input        | Program/program inhibit input in PROM programming mode.  |
| V <sub>DD</sub> | _            | Positive power supply  |
| Vss             | _            | Ground potential   |

## 2.3 Pin Input/Output Circuits and Recommended Connection of Unused Pins

Types of input/output circuits of the pins and recommeded connection of unused pins are shown in Table 2-1. For the configuration of each type of input/output circuit, see Figure 2-1.

Table 2-1. Type of Input/Output Circuit of Each Pin

| Pin Name          | Input/Output | Input/Output | Recommended Connection for Unused Pins       |
|-------------------|--------------|--------------|--|
|                   | Circuit Type |              |  |
| P00               | 2            | Input        | Connect to Vss.                              |
| P01/INTP1         | 8-A          | Input/Output | Independently connect to Vss via a resistor. |
| P02/INTP2         |              |              |  |
| P03/INTP3         |              |              |  |
| P10/ANI0-P17/ANI7 | 11           | Input/Output | Independently connect to VDD or Vss via      |
| P30-P32           | 5-A          |              | a resistor.                                  |
| P33, P34          | 8-A          |              |  |
| P35/PCL           | 5-A          |              |  |
| P36/BUZ           |              |              |  |
| P37               |              |              |  |
| P50-P57           | 5-A          |              |  |
| P70/SI2/RxD       | 8-A          |              |  |
| P71/SO2/TxD       | 5-A          |              |  |
| P72/SCK2/ASCK     | 8-A          |              |  |
| P100/TI5/TO5      | 8-A          |              |  |
| P101/TI6/TO6      |              |              |  |
| RESET             | 2            | Input        | _  |
| AVREF             | _            | -            | Connect to Vss.                              |
| AVDD              |              |              | Connect to VDD.                              |
| AVss              |              |              | Connect to Vss.                              |
| VPP               |              |              | Connect directly to Vss.                     |
| NC                |              |              | Connect to Vss (can leave open)              |



Type 2 Type 8-A pull-up enable IN O V<sub>DD</sub> data--○ IN/OUT output Schmitt-triggered input with hysteresis characteristics disable V<sub>DD</sub> ↓ Type 5-A Type 11 pull-up enable pull-up enable  $V_{\text{DD}}$ data -○ IN/OUT dataoutput disable -○ IN/OUT output Comparator disable V<sub>REF</sub> (threshold voltage) input enable input enable

Figure 2-1. Types of Pin Input/Output Circuits



## 3. INTERNAL MEMORY SIZE SWITCHING REGISTER (IMS)

This is a register to disable use of part of internal memories by software. By setting this internal memory size switching register (IMS), it is possible to get the same memory mapping as that of the mask ROM versions with a different internal memory (ROM, RAM).

IMS is set with an 8-bit memory manipulation instruction.

RESET input sets IMS to 46H.

Figure 3-1. Internal Memory Size Switching Register Format

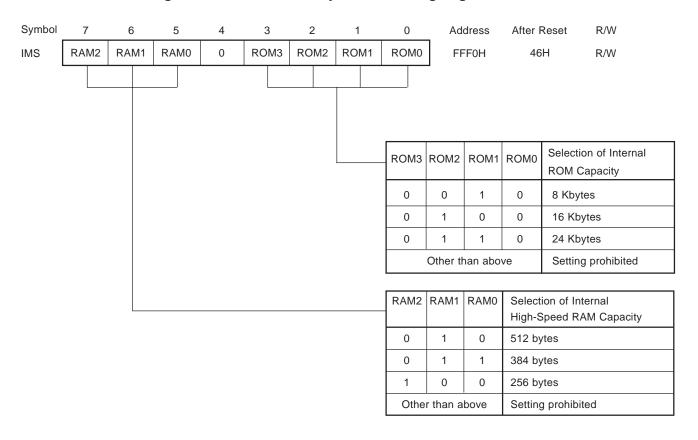


Table 3-1 shows the setting values of IMS which make the memory mapping the same as that of the mask ROM version.

Table 3-1. Internal Memory Size Switching Register Setting Values

| Target Mask ROM Versions | IMS Setting Value |
|--------------------------|-------------------|
| μPD78081                 | 82H               |
| μPD78082                 | 64H               |



#### 4. PROM PROGRAMMING

The μPD78P083 has an internal 24-Kbyte PROM as a program memory. For programming, set the PROM programming mode with the VPP and RESET pins. For the connection of unused pins, refer to "PIN CONFIGURATIONS (TOP VIEW) (2) PROM programming mode."

Caution Programs must be written in addresses 0000H to 5FFFH (The last address 5FFFH must be specified). They cannot be written by a PROM programmer which cannot specify the write address.

#### **Operating Modes**

When +5 V or +12.5 V is applied to the VPP pin and a low-level signal is applied to the RESET pin, the PROM programming mode is set. This mode will become the operating mode as shown in Table 4-1 when the CE, OE, and PGM pins are set as shown.

Further, when the read mode is set, it is possible to read the contents of the PROM.

CE ŌĒ PGM RESET Pin  $V_{PP}$  $V_{\text{DD}}$ D0 to D7 Operating Mode Page data latch L +12.5 V +6.5 V Н L Н Data input Н Page write Н L High-impedance Byte write L Н L Data input L Н Program verify L Data output Н Н Program inhibit Х High-impedance х L L +5 V +5 V L Н Read L Data output Output disable L Н High-impedance Х Н High-impedance

Х

Х

Table 4-1. Operating Modes of PROM Programming

Standby x:LorH



#### (1) Read mode

Read mode is set if  $\overline{CE} = L$ ,  $\overline{OE} = L$  is set.

#### (2) Output disable mode

Data output becomes high-impedance, and is in the output disable mode, if  $\overline{OE} = H$  is set.

Therefore, it allows data to be read from any device by controlling the  $\overline{\text{OE}}$  pin, if multiple  $\mu$ PD78P083s are connected to the data bus.

### (3) Standby mode

Standby mode is set if  $\overline{CE} = H$  is set.

In this mode, data outputs become high-impedance irrespective of the  $\overline{OE}$  status.

#### (4) Page data latch mode

Page data latch mode is set if  $\overline{CE} = H$ ,  $\overline{PGM} = H$ ,  $\overline{OE} = L$  are set at the beginning of page write mode. In this mode, 1 page 4-byte data is latched in an internal address/data latch circuit.

#### (5) Page write mode

After 1 page 4 bytes of addresses and data are latched in the page data latch mode, a page write is executed by applying a 0.1-ms program pulse (active low) to the  $\overline{\text{PGM}}$  pin with  $\overline{\text{CE}} = \text{H}$ ,  $\overline{\text{OE}} = \text{H}$ . Then, program verification can be performed, if  $\overline{\text{CE}} = \text{L}$ ,  $\overline{\text{OE}} = \text{L}$  are set.

If programming is not performed by a one-time program pulse, X times ( $X \le 10$ ) write and verification operations should be executed repeatedly.

### (6) Byte write mode

Byte write is executed when a 0.1-ms program pulse (active low) is applied to the  $\overline{PGM}$  pin with  $\overline{CE} = L$ ,  $\overline{OE} = H$ . Then, program verification can be performed if  $\overline{OE} = L$  is set.

If programming is not performed by a one-time program pulse, X times ( $X \le 10$ ) write and verification operations should be executed repeatedly.

#### (7) Program verify mode

Program verify mode is set if  $\overline{CE} = L$ ,  $\overline{PGM} = H$ ,  $\overline{OE} = L$  are set.

In this mode, check if a write operation is performed correctly after the write.

## (8) Program inhibit mode

Program inhibit mode is used when the  $\overline{\text{OE}}$  pin, VPP pin, and D0-D7 pins of multiple  $\mu$ PD78P083s are connected in parallel and a write is performed to one of those devices.

When a write operation is performed, the page write mode or byte write mode described above is used. At this time, a write is not performed to a device which has the  $\overline{\text{PGM}}$  pin driven high.



#### 4.2 PROM Write Procedure

Start Address = G $V_{DD} = +6.5 \text{ V}, V_{PP} = +12.5 \text{ V}$ X = 0Latch Address = Address + 1 Latch Address = Address + 1 Latch Address = Address + 1 Address = Address + 1 Latch No X = X + 1Yes X = 10 ? 0.1-ms program pulse Fail Verify 4 bytes Pass Address = N ? Yes  $V_{\text{DD}} = 4.5 \text{ to } 5.5 \text{ V}, \, V_{\text{PP}} = V_{\text{DD}}$ Pass Fail Verify all bytes All Pass Write end Defective product

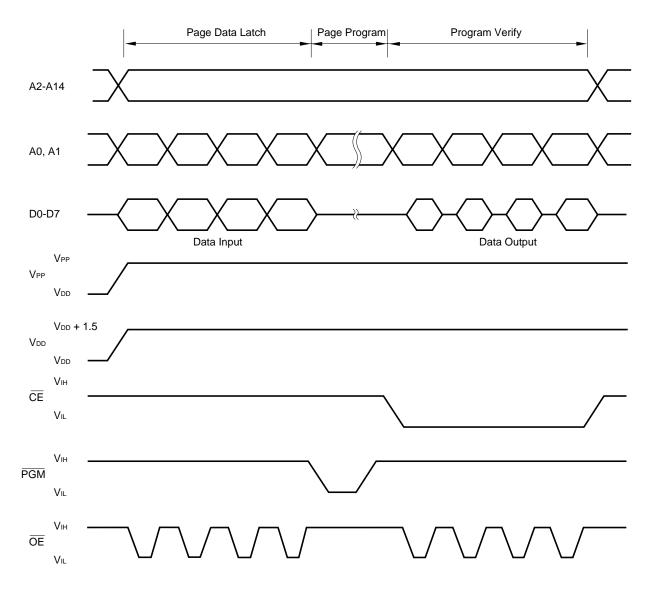
Figure 4-1. Page Program Mode Flow Chart

G = Start address

N = Program last address



Figure 4-2. Page Program Mode Timing





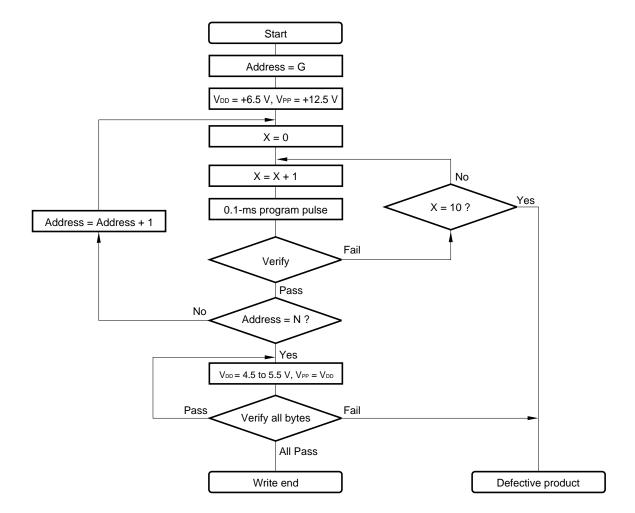


Figure 4-3. Byte Program Mode Flow Chart

G = Start address

N = Program last address



Program Program Verify A0-A14 D0-D7 Data Input Data Output  $V_{PP}$  $V_{\text{DD}}$  $V_{DD} + 1.5$  $V_{\text{DD}}$  $V_{\text{DD}}$ CE  $V_{\mathsf{IL}}$  $\overline{\mathsf{PGM}}$  $V_{\mathsf{IL}}$  $\overline{\text{OE}}$  $V_{\mathsf{IL}}$ 

Figure 4-4. Byte Program Mode Timing

- Cautions 1. VDD should be applied before VPP and removed after VPP.
  - 2. VPP must not exceed +13.5 V including overshoot.
  - 3. Reliability may be adversely affected if removal/reinsertion is performed while +12.5 V is being applied to VPP.



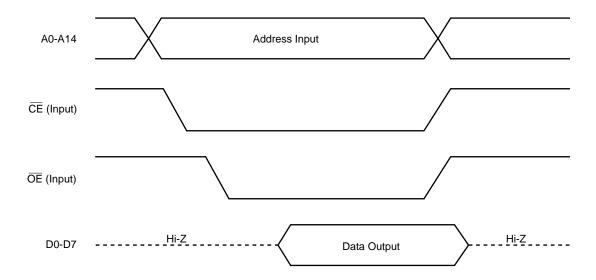
#### 4.3 PROM Read Procedure

The contents of PROM are readable to the external data bus (D0-D7) according to the read procedure shown below.

- (1) Fix the RESET pin at low level, supply +5 V to the VPP pin, and connect all other unused pins as shown in "PIN CONFIGURATIONS (TOP VIEW) (2) PROM programming mode".
- (2) Supply +5 V to the VDD and VPP pins.
- (3) Input address of read data into the A0-A16 pins.
- (4) Read mode
- (5) Output data to D0-D7 pins.

The timings of the above steps (2) to (5) are shown in Figure 4-5.

Figure 4-5. PROM Read Timings





## \* 5. PROGRAM ERASURE (μPD78P083DU ONLY)

The μPD78P083DU is capable of erasing (FFH) the data written in a program memory and rewriting.

To erase the programmed data, expose the erasure window to light having a wavelength shorter than about 400 nm. Normally, irradiate ultraviolet rays of 254-nm wavelength. The amount of exposure required to completely erase the programmed data is as follows:

• UV intensity x erasing time : 30 W•s/cm² or more

 Erasure time: 40 min. or more (When a UV lamp of 12,000 μW/cm² is used. However, a longer time may be needed because of deterioration in performance of the UV lamp, soiled erasure window, etc.)

When erasing the contents of data, set up the UV lamp within 2.5 cm from the erasure window. Further, if a filter is provided for a UV lamp, irradiate the ultraviolet rays after removing the filter.

#### 6. OPAQUE FILM ON ERASURE WINDOW (μPD78P083DU ONLY)

To protect from unintentional erasure by rays other than that of the lamp for erasing EPROM contents, or to protect internal circuit other than EPROM from misoperating by rays, cover the erasure window with an opaque film when EPROM contents erasure is not performed.

#### 7. ONE-TIME PROM VERSION SCREENING

The one-time PROM version (µPD78P083CU, 78P083GB-3B4, 78P083GB-3BS-MTX) cannot be tested completely by NEC before it is shipped, because of its structure. It is recommended to perform screening to verify PROM after writing necessary data and performing high-temperature storage under the condition below.

| Storage Temperature | Storage Time |
|---------------------|--------------|
| 125°C               | 24 hours     |

\* NEC offers for an additional fee one-time PROM writing to marking, screening, and verify for products designated as "QTOP Microcontroller". Please contact an NEC sales representative for details.

\*



### 8. ELECTRICAL SPECIFICATIONS

**Absolute Maximum Ratings**  $(TA = 25^{\circ}C)$ 

| Parameter                     | Symbol               | Test Conditions                      | Test Conditions |                              |                               | Unit |
|-------------------------------|----------------------|--------------------------------------|-----------------|------------------------------|-------------------------------|------|
| Supply voltage                | V <sub>DD</sub>      |                                      |                 |                              | -0.3 to +7.0                  | V    |
|                               | V <sub>PP</sub>      |                                      |                 |                              | -0.3 to +13.5                 | V    |
|                               | AV <sub>DD</sub>     |                                      |                 |                              | -0.3 to V <sub>DD</sub> + 0.3 | V    |
|                               | AVREF                |                                      |                 |                              | -0.3 to V <sub>DD</sub> + 0.3 | V    |
|                               | AVss                 |                                      |                 |                              | -0.3 to +0.3                  | V    |
| Input voltage                 | VI1                  |                                      |                 |                              | -0.3 to V <sub>DD</sub> + 0.3 | V    |
|                               | V <sub>I2</sub>      | A9                                   | PROM progr      | ramming mode                 | -0.3 to +13.5                 | V    |
| Output voltage                | Vo                   |                                      |                 |                              |                               | V    |
| Analog input voltage          | Van                  | P10-P17                              | Analog inp      | ut pins                      | AVss - 0.3 to AVREF + 0.3     | V    |
| Output current, high          | Іон                  | Per pin                              | 1               |                              | -10                           | mA   |
|                               |                      | Total for P10-P17, P50-P54, P70-P72, |                 |                              | -15                           | mA   |
|                               |                      | P100, P101                           |                 |                              |                               |      |
|                               |                      | Total for P01-P03, P30-              | P37, P55-P5     | -15                          | mA                            |      |
| Output current, low           | I <sub>OL</sub> Note | Per pin                              |                 | Peak value                   | 30                            | mA   |
|                               |                      |                                      |                 |                              | 15                            | mA   |
|                               |                      | _                                    |                 | Peak value                   | 100                           | mA   |
|                               |                      |                                      |                 | r.m.s. value                 | 70                            | mA   |
|                               |                      | Total for P55-P57 Peak value 100     |                 | Total for P55-P57 Peak value |                               | mA   |
|                               |                      |                                      |                 | r.m.s. value                 | 70                            | mA   |
|                               |                      | Total for P10-P17, P70-P             | 72, P100,       | Peak value                   | 50                            | mA   |
|                               |                      | P101                                 |                 | r.m.s. value                 | 20                            | mA   |
|                               |                      | Total for P01-P03, P30-              | -P37            | Peak value                   | 50                            | mA   |
|                               |                      |                                      |                 | r.m.s. value                 | 20                            | mA   |
| Operating ambient temperature | TA                   |                                      |                 | •                            | -40 to +85                    | °C   |
| Storage temperature           | T <sub>stg</sub>     |                                      |                 |                              | -65 to +150                   | °C   |

**Note** The r.m.s. value should be calculated as follows: [r.m.s. value] = [Peak value]  $x \sqrt{\text{Duty}}$ 

Caution If the absolute maximum rating of even one of the above parameters is exceeded, the quality of the product may be degraded. The absolute maximum ratings are therefore the rated values that may, if exceeded, physically damage the product. Be sure to use the product with all the absolute maximum ratings observed.

**Remark** Unless otherwise specified, dual-function pin characteristics are the same as port pin characteristics.



## Capacitance (TA = 25°C, VDD = Vss = 0 V)

| Parameter         | Symbol | Test Conditions                             |                         |  | TYP. | MAX. | Unit |
|-------------------|--------|---|-------------------------|--|------|------|------|
| Input capacitance | Cin    | f = 1 MHz, Unmeasured pins returned to 0 V. |                         |  |      | 15   | pF   |
| I/O capacitance   | Сю     | f = 1 MHz, P01-P03, P10-P17, P30-P37,       |                         |  |      | 15   | pF   |
|                   |        | Unmeasured pins                             | P50-P57, P70-P72, P100, |  |      |      |      |
|                   |        | returned to 0 V.                            | P101                    |  |      |      |      |

**Remark** Unless otherwise specified, dual-function pin characteristics are the same as port pin characteristics.

## Main System Clock Oscillator Characteristics ( $TA = -40 \text{ to } +85^{\circ}\text{C}$ , VDD = 1.8 to 5.5 V)

| Resonator         | Recommended<br>Circuit | Parameter                             | Test Conditions   | MIN. | TYP. | MAX. | Unit |
|-------------------|------------------------|---------------------------------------|---|------|------|------|------|
| Ceramic resonator | VPP X2 X1              | Oscillation frequency (fx) Note 1     | V <sub>DD</sub> = Oscillation voltage range                     | 1.0  |      | 5.0  | MHz  |
|                   | C2+ C1 + 1             | Oscillation stabilization time Note 2 | After V <sub>DD</sub> came to MIN. of oscillation voltage range |      |      | 4    | ms   |
| Crystal resonator | VPP X2 X1              | Oscillation frequency (fx) Note 1     |   | 1.0  |      | 5.0  | MHz  |
|                   |                        | Oscillation stabilization             | V <sub>DD</sub> = 4.5 to 5.5 V                                  |      |      | 10   | ms   |
|                   | 1777                   | time Note 2                           |   |      |      | 30   |      |
| External clock    | X2 X1                  | X1 input frequency (fx) Note 1        |   | 1.0  |      | 5.0  | MHz  |
|                   | μPD74HCU04 Λ           | X1 input high- and                    |   | 85   |      | 500  | ns   |
|                   | <u> </u>               | low-level widths (txH, txL)           |   |      |      |      |      |

- Notes 1. Only the oscillator characteristics are shown. For the instruction execution time, refer to AC Characteristics.
  - 2. Time required for oscillation to stabilize after a reset or the STOP mode has been released.

Caution When using the oscillation circuit of the main system clock, wire the portion enclosed in broken lines in the figures as follows to avoid adverse influences on the wiring capacitance:

- Keep the wiring length as short as possible.
- · Do not cross the wiring over other signal lines.
- Do not route the wiring in the vicinity of lines through which a high fluctuating current flows.
- · Always keep the ground point of the capacitor of the oscillation circuit at the same potential as Vss.
- Do not connect the power source pattern through which a high current flows.
- · Do not extract signals from the oscillation circuit.



# **DC Characteristics** (TA = -40 to +85°C, VDD = 1.8 to 5.5 V)

| Parameter                 | Symbol            | Test Co                                     | onditions                                | MIN.                 | TYP. | MAX.                | Unit |
|---------------------------|-------------------|---|--|----------------------|------|---------------------|------|
| Input voltage, high       | V <sub>IH1</sub>  | P10-P17, P30-P32,<br>P35-P37, P50-P57,      | V <sub>DD</sub> = 2.7 to 5.5 V           | 0.7V <sub>DD</sub>   |      | V <sub>DD</sub>     | V    |
|                           |                   | P71   |  | 0.8V <sub>DD</sub>   |      | V <sub>DD</sub>     | V    |
|                           | V <sub>IH2</sub>  | P00-P03, P33, P34,<br>P70, P72, P100, P101, | V <sub>DD</sub> = 2.7 to 5.5 V           | 0.8V <sub>DD</sub>   |      | V <sub>DD</sub>     | V    |
|                           |                   | RESET                                       |  | 0.85V <sub>DD</sub>  |      | V <sub>DD</sub>     | V    |
|                           | VIH3              | X1, X2                                      | $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$ | Vpp-0.5              |      | V <sub>DD</sub>     | V    |
|                           |                   |   |  | Vpp-0.2              |      | V <sub>DD</sub>     | V    |
| Input voltage, low        | V <sub>IL1</sub>  | P10-P17, P30-P32,                           | $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$ | 0                    |      | 0.3V <sub>DD</sub>  | V    |
|                           |                   | P35-P37, P50-P57,                           |  |                      |      |                     |      |
|                           |                   | P71   |  | 0                    |      | 0.2V <sub>DD</sub>  | V    |
|                           | V <sub>IL2</sub>  | P00-P03, P33, P34,<br>P70, P72, P100,       | V <sub>DD</sub> = 2.7 to 5.5 V           | 0                    |      | 0.2V <sub>DD</sub>  | V    |
|                           |                   | P101, RESET                                 |  | 0                    |      | 0.15V <sub>DD</sub> | V    |
|                           | V <sub>IL3</sub>  | X1, X2                                      | V <sub>DD</sub> = 2.7 to 5.5 V           | 0                    |      | 0.4                 | V    |
|                           |                   |   |  | 0                    |      | 0.2                 | V    |
| Output voltage, high      | Vон               | V <sub>DD</sub> = 4.5 to 5.5 V, Іон         | = -1 mA                                  | V <sub>DD</sub> -1.0 |      |                     | V    |
|                           |                   | Іон = -100 μΑ                               |  | V <sub>DD</sub> -0.5 |      |                     | V    |
| Output voltage, low       | Vol               | P50-P57                                     | V <sub>DD</sub> = 2.0 to 4.5 V,          |                      |      | 0.8                 | V    |
| ,                         |                   |   | IoL = 10 mA                              |                      |      |                     |      |
|                           |                   |   | V <sub>DD</sub> = 4.5 to 5.5 V,          |                      | 0.4  | 2.0                 | V    |
|                           |                   |   | IoL = 15 mA                              |                      |      |                     |      |
|                           |                   | P01-P03, P10-P17,                           | V <sub>DD</sub> = 4.5 to 5.5 V,          |                      |      | 0.4                 | V    |
|                           |                   | P30-P37, P70-P72,                           | IoL = 1.6 mA                             |                      |      |                     |      |
|                           |                   | P100, P101                                  | Ιοι = 400 μΑ                             |                      |      | 0.5                 | V    |
| Input-leak current, high  | ILIH1             | VIN = VDD                                   | P00-P03, P10-P17,                        |                      |      | 3                   | μΑ   |
|                           |                   |   | P30-P37, P50-P57,                        |                      |      |                     |      |
|                           |                   |   | P70-P72, P100,                           |                      |      |                     |      |
|                           |                   |   | P101, RESET                              |                      |      |                     |      |
|                           | I <sub>LIH2</sub> |   | X1, X2                                   |                      |      | 20                  | μΑ   |
| Input-leak current, low   | ILIL1             | VIN = 0 V                                   | P00-P03, P10-P17,                        |                      |      | -3                  | μΑ   |
|                           |                   |   | P30-P37, P50-P57,                        |                      |      |                     |      |
|                           |                   |   | P70-P72, P100,                           |                      |      |                     |      |
|                           |                   |   | P101, RESET                              |                      |      |                     |      |
|                           | I <sub>LIL2</sub> |   | X1, X2                                   |                      |      | -20                 | μΑ   |
| Output leak current, high | Ісон              | Vout = Vdd                                  | 1  |                      |      | 3                   | μΑ   |
| Output leak current, low  | ILOL              | Vout = 0 V                                  |  |                      |      | -3                  | μΑ   |
| Software pull-up resistor | R                 | VIN = 0 V                                   | P01-P03, P10-P17,                        | 15                   | 40   | 90                  | kΩ   |
|                           |                   |   | P30-P37, P50-P57,                        |                      |      |                     |      |
|                           |                   |   | P70-P72, P100,                           |                      |      |                     |      |
|                           |                   |   | P101                                     |                      |      |                     |      |

Remark Unless otherwise specified, dual-function pin characteristics are the same as port pin characteristics.



## **DC Characteristics** (TA = -40 to +85°C, VDD = 1.8 to 5.5 V)

| Parameter             | Symbol           | Test Co                                   | nditions                                 | MIN. | TYP. | MAX. | Unit |
|-----------------------|------------------|---|--|------|------|------|------|
| Supply current Note 1 | I <sub>DD1</sub> | 5.0-MHz crystal                           | $V_{DD} = 5.0 \text{ V} \pm 10\%$ Note 4 |      | 5.4  | 16.2 | mA   |
|                       |                  | oscillation operating                     | $V_{DD} = 3.0 \text{ V} \pm 10\%$ Note 5 |      | 0.8  | 2.4  | mA   |
|                       |                  | mode (fxx = 2.5 MHz) Note 2               | $V_{DD}$ = 2.0 $V \pm 10\%$ Note 5       |      | 0.45 | 1.35 | mA   |
|                       |                  | 5.0-MHz crystal oscil-                    | $V_{DD} = 5.0 \text{ V} \pm 10\%$ Note 4 |      | 9.5  | 28.5 | mA   |
|                       |                  | lation operating mode                     | $V_{DD} = 3.0 \text{ V} \pm 10\%$ Note 5 |      | 1.0  | 3.0  | mA   |
|                       |                  | $(fxx = 5.0 \text{ MHz})^{\text{Note 3}}$ |  |      |      |      |      |
|                       | I <sub>DD2</sub> | 5.0-MHz crystal oscil-                    | $V_{DD} = 5.0 \text{ V} \pm 10\%$        |      | 1.4  | 4.2  | mA   |
|                       |                  | lation HALT mode                          | $V_{DD} = 3.0 \text{ V} \pm 10\%$        |      | 0.5  | 1.5  | mA   |
|                       |                  | (fxx = 2.5 MHz) Note 2                    | V <sub>DD</sub> = 2.0 V ± 10%            |      | 280  | 840  | μΑ   |
|                       |                  | 5.0-MHz crystal oscil-                    | $V_{DD} = 5.0 \text{ V} \pm 10\%$        |      | 1.6  | 4.8  | mA   |
|                       |                  | lation HALT mode                          | $V_{DD} = 3.0 \text{ V} \pm 10\%$        |      | 0.65 | 1.95 | mA   |
|                       |                  | $(fxx = 5.0 \text{ MHz})^{\text{Note 3}}$ |  |      |      |      |      |
|                       | I <sub>DD3</sub> | STOP mode                                 | $V_{DD} = 5.0 \text{ V} \pm 10\%$        |      | 0.1  | 30   | μΑ   |
|                       |                  |   | $V_{DD} = 3.0 \text{ V} \pm 10\%$        |      | 0.05 | 10   | μΑ   |
|                       |                  |   | $V_{DD} = 2.0 \text{ V} \pm 10\%$        |      | 0.05 | 10   | μΑ   |

Notes 1. Not including AVREF, AVDD currents or port currents (including current flowing into internal pull-up resistors).

- **2.** fxx = fx/2 operation (when oscillation mode selection register (OSMS) is set to 00H).
- **3.** fxx = fx operation (when oscillation mode selection register (OSMS) is set to 01H).
- 4. High-speed mode operation (when processor clock control register (PCC) is set to 00H).
- 5. Low-speed mode operation (when processor clock control register (PCC) is set to 04H).

**Remark** fxx: Main system clock frequency (fx or fx/2)

fx: Main system clock oscillation frequency



## **AC Characteristics**

(1) **Basic Operation** (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

| Parameter                      | Symbol | Test                                     | t Conditions  | MIN. | TYP. | MAX. | Unit |
|--------------------------------|--------|--|---|------|------|------|------|
| Cycle time                     | Тсч    | fxx = fx/2 Note1                         | V <sub>DD</sub> = 2.7 to 5.5 V                        | 0.8  |      | 64   | μs   |
| (minimum instruction execution |        |  |   | 2.0  |      | 64   | μs   |
| time)                          |        | $fxx = fx^{Note2}$                       | $3.5 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$ | 0.4  |      | 32   | μs   |
|                                |        |  | 2.7 V ≤ V <sub>DD</sub> < 3.5 V                       | 0.8  |      | 32   | μs   |
| TI5, TI6                       | f⊤ı    | $V_{DD} = 4.5 \text{ to } 5.5 \text{ V}$ |   | 0    |      | 4    | MHz  |
| input frequency                |        |  |   | 0    |      | 275  | kHz  |
| TI5, TI6 input high-/          | tтıн,  | V <sub>DD</sub> = 4.5 to 5.5 V           |   | 100  |      |      | ns   |
| low-level widths               | t⊤ı∟   |  |   | 1.8  |      |      | μs   |
| Interrupt input high-/         | tinth, | V <sub>DD</sub> = 2.7 to 5.5 V           |   | 10   |      |      | μs   |
| low-level widths               | tintl  |  |   | 20   |      |      | μs   |
| RESET low-level width          | trsl   | V <sub>DD</sub> = 2.7 to 5.5 V           |   | 10   |      |      | μs   |
|                                |        |  |   | 20   |      |      | μs   |

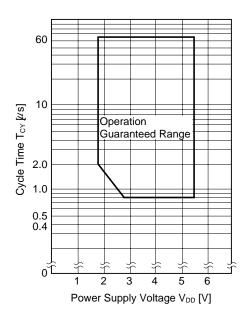
Notes 1. When oscillation mode selection register (OSMS) is set to 00H.

2. When OSMS is set to 01H.

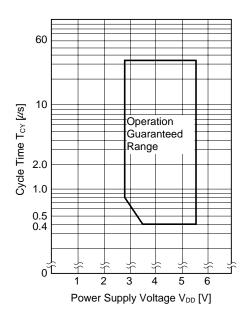
Remark fxx: Main system clock frequency (fx or fx/2)

fx: Main system clock oscillation frequency

Tcy vs  $V_{DD}$ (Main System Clock  $f_{xx} = f_x/2$  Operation)



TCY VS VDD (Main System Clock  $f_{xx} = f_x$  Operation)





## (2) **Serial Interface** $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{DD} = 1.8 \text{ to } 5.5 \text{ V})$

(a) 3-wire serial I/O mode (\$\overline{SCK2} \cdots internal clock output)

| Parameter                           | Symbol           | Test Conditions                 | MIN.        | TYP. | MAX. | Unit |
|-------------------------------------|------------------|---------------------------------|-------------|------|------|------|
| SCK2 cycle time                     | tkcY1            | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 V | 800         |      |      | ns   |
|                                     |                  | 2.7 V ≤ V <sub>DD</sub> < 4.5 V | 1600        |      |      | ns   |
|                                     |                  | 2.0 V ≤ V <sub>DD</sub> < 2.7 V | 3200        |      |      | ns   |
|                                     |                  |                                 | 4800        |      |      | ns   |
| SCK2 high-/low-level width          | <b>t</b> кн1,    | V <sub>DD</sub> = 4.5 to 5.5 V  | tkcy1/2-50  |      |      | ns   |
|                                     | t <sub>KL1</sub> |                                 | tkcy1/2-100 |      |      | ns   |
| SI2 setup time                      | tsik1            | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 V | 100         |      |      | ns   |
| (to SCK2 ↑)                         |                  | 2.7 V ≤ V <sub>DD</sub> < 4.5 V | 150         |      |      | ns   |
|                                     |                  | 2.0 V ≤ V <sub>DD</sub> < 2.7 V | 300         |      |      | ns   |
|                                     |                  |                                 | 400         |      |      | ns   |
| SI2 hold time                       | tksi1            |                                 | 400         |      |      | ns   |
| (from SCK2 ↑)                       |                  |                                 |             |      |      |      |
| $\overline{SCK2}\downarrow \to SO2$ | tkso1            | C = 100 pF <sup>Note</sup>      |             |      | 300  | ns   |
| output delay time                   |                  |                                 |             |      |      |      |

Note C is the  $\overline{\text{SCK2}}$ , SO2 output line load capacitance.

(b) 3-wire serial I/O mode (SCK2 ··· external clock input)

| Parameter                            | Symbol            | Test Co                         | onditions                      | MIN. | TYP. | MAX. | Unit |
|--------------------------------------|-------------------|---------------------------------|--------------------------------|------|------|------|------|
| SCK2 cycle time                      | tkcy2             | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 \ | J                              | 800  |      |      | ns   |
|                                      |                   | 2.7 V ≤ V <sub>DD</sub> < 4.5 \ | J                              | 1600 |      |      | ns   |
|                                      |                   | 2.0 V ≤ V <sub>DD</sub> < 2.7 \ | J                              | 3200 |      |      | ns   |
|                                      |                   |                                 |                                | 4800 |      |      | ns   |
| SCK2 high-/low-level width           | <b>t</b> кн2,     | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 \ | /                              | 400  |      |      | ns   |
|                                      | t <sub>KL2</sub>  | 2.7 V ≤ V <sub>DD</sub> < 4.5 \ | J                              | 800  |      |      | ns   |
|                                      |                   | 2.0 V ≤ V <sub>DD</sub> < 2.7 \ | J                              | 1600 |      |      | ns   |
|                                      |                   |                                 |                                | 2400 |      |      | ns   |
| SI2 setup time                       | tsik2             | V <sub>DD</sub> = 2.0 to 5.5 V  |                                | 100  |      |      | ns   |
| (to SCK2 ↑)                          |                   |                                 |                                | 150  |      |      | ns   |
| SI2 hold time                        | tksi2             |                                 |                                | 400  |      |      | ns   |
| (from SCK2 ↑)                        |                   |                                 |                                |      |      |      |      |
| $\overline{SCK2} \downarrow \to SO2$ | tkso2             | C = 100 pF <sup>Note</sup>      | V <sub>DD</sub> = 2.0 to 5.5 V |      |      | 300  | ns   |
| output delay time                    |                   |                                 |                                |      |      | 500  | ns   |
| SCK2 rise, fall time                 | t <sub>R2</sub> , |                                 |                                |      |      | 1000 | ns   |
|                                      | t <sub>F2</sub>   |                                 |                                |      |      |      |      |

Note C is the SO2 output line load capacitance.



## (c) UART mode (Dedicated baud rate generator output)

| Parameter     | Symbol | Test Conditions                 | MIN. | TYP. | MAX.  | Unit |
|---------------|--------|---------------------------------|------|------|-------|------|
| Transfer rate |        | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 V |      |      | 78125 | bps  |
|               |        | 2.7 V ≤ V <sub>DD</sub> < 4.5 V |      |      | 39063 | bps  |
|               |        | 2.0 V ≤ V <sub>DD</sub> < 2.7 V |      |      | 19531 | bps  |
|               |        |                                 |      |      | 9766  | bps  |

## (d) UART mode (External clock input)

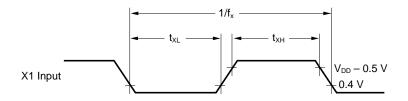
| Parameter                  | Symbol            | Test Conditions                 | MIN. | TYP. | MAX.  | Unit |
|----------------------------|-------------------|---------------------------------|------|------|-------|------|
| ASCK cycle time            | tксүз             | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 V | 800  |      |       | ns   |
|                            |                   | 2.7 V ≤ V <sub>DD</sub> < 4.5 V | 1600 |      |       | ns   |
|                            |                   | 2.0 V ≤ V <sub>DD</sub> < 2.7 V | 3200 |      |       | ns   |
|                            |                   |                                 | 4800 |      |       | ns   |
| ASCK high-/low-level width | <b>t</b> кнз,     | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 V | 400  |      |       | ns   |
|                            | tкLз              | 2.7 V ≤ V <sub>DD</sub> < 4.5 V | 800  |      |       | ns   |
|                            |                   | 2.0 V ≤ V <sub>DD</sub> < 2.7 V | 1600 |      |       | ns   |
|                            |                   |                                 | 2400 |      |       | ns   |
| Transfer rate              |                   | 4.5 V ≤ V <sub>DD</sub> ≤ 5.5 V |      |      | 39063 | bps  |
|                            |                   | 2.7 V ≤ V <sub>DD</sub> < 4.5 V |      |      | 19531 | bps  |
|                            |                   | 2.0 V ≤ V <sub>DD</sub> < 2.7 V |      |      | 9766  | bps  |
|                            |                   |                                 |      |      | 6510  | bps  |
| ASCK rise, fall time       | t <sub>R3</sub> , |                                 |      |      | 1000  | ns   |
|                            | tғз               |                                 |      |      |       |      |



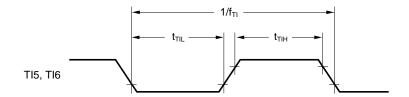
# AC Timing Test Point (Excluding X1 Input)



## **Clock Timing**



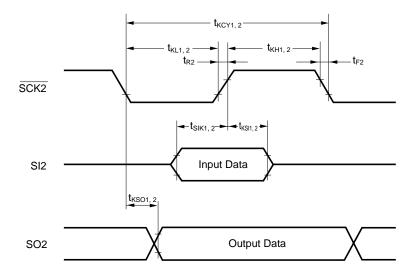
## **TI Timing**



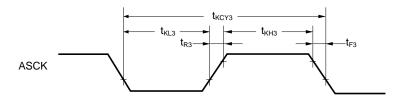


## **Serial Transfer Timing**

## 3-wire serial I/O mode:



## **UART** mode (external clock input):





## A/D Converter Characteristics ( $TA = -40 \text{ to } +85^{\circ}\text{C}$ , AVDD = VDD = 2.7 to 5.5 V, AVSS = VSS = 0 V)

| Parameter             | Symbol | Test Conditions                              | MIN.               | TYP. | MAX.             | Unit |
|-----------------------|--------|--|--------------------|------|------------------|------|
| Resolution            |        |  | 8                  | 8    | 8                | bit  |
| Total error Note      |        | 2.7 V ≤ AV <sub>REF</sub> ≤ AV <sub>DD</sub> |                    |      | 1.4              | %    |
| Conversion time       | tconv  |  | 19.1               |      | 200              | μs   |
| Sampling time         | tsamp  |  | 12/f <sub>xx</sub> |      |                  | μs   |
| Analog input voltage  | VIAN   |  | AVss               |      | AVREF            | V    |
| Reference voltage     | AVREF  |  | 2.7                |      | AV <sub>DD</sub> | V    |
| AVREF-AVss resistance | Rairef |  | 4                  | 14   |                  | kΩ   |

**Note** Excluding quantization error ( $\pm 1/2$  LSB). Shown as a percentage of the full scale value.

**Remark**  $f_{xx}$ : Main system clock frequency ( $f_x$  or  $f_x/2$ )

fx: Main system clock oscillation frequency



## Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics ( $TA = -40 \text{ to } +85^{\circ}\text{C}$ )

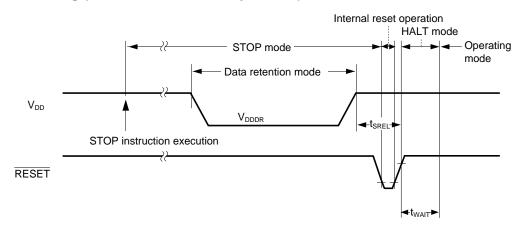
| Parameter                      | Symbol | Test Conditions      | MIN. | TYP.   | MAX. | Unit |
|--------------------------------|--------|----------------------|------|--------|------|------|
| Data retention supply voltage  | VDDDR  |                      | 1.8  |        | 5.5  | V    |
| Data retention supply current  | Idddr  | VDDDR = 1.8 V        |      | 0.1    | 10   | μΑ   |
| Release signal set time        | tsrel  |                      | 0    |        |      | μs   |
| Oscillation stabilization wait | twait  | Release by RESET     |      | 217/fx |      | ms   |
| time                           |        | Release by interrupt |      | Note   |      | ms   |

Note 2<sup>12</sup>/f<sub>xx</sub> or 2<sup>14</sup>/f<sub>xx</sub>-2<sup>17</sup>/f<sub>xx</sub> can be selected by bit 0-bit 2 (OSTS0-OSTS2) of oscillation stabilization time selection register (OSTS).

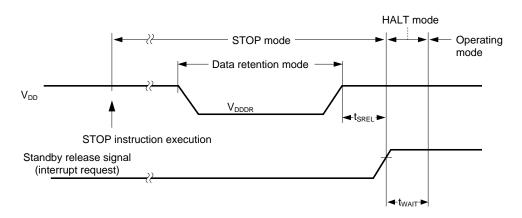
**Remark** fxx: Main system clock frequency (fx or fx/2)

fx: Main system clock oscillation frequency

# Data Retention Timing (STOP mode released by RESET)

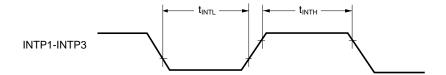


## Data Retention Timing (Standby release signal: STOP mode released by interrupt signal)

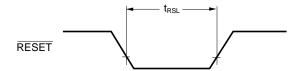




# **Interrupt Input Timing**



# **RESET** Input Timing





# **PROM Programming Characteristics**

## **DC Characteristics**

## (1) **PROM Write Mode** (TA = $25 \pm 5^{\circ}$ C, VDD = $6.5 \pm 0.25$ V, VPP = $12.5 \pm 0.3$ V)

| Parameter                      | Symbol          | Symbol <sup>Note</sup> | Test Conditions           | MIN.                  | TYP. | MAX.            | Unit |
|--------------------------------|-----------------|------------------------|---------------------------|-----------------------|------|-----------------|------|
| Input voltage, high            | ViH             | ViH                    |                           | 0.7V <sub>DD</sub>    |      | V <sub>DD</sub> | V    |
| Input voltage, low             | VIL             | VIL                    |                           | 0                     |      | 0.3Vpd          | V    |
| Output voltage, high           | Vон             | Vон                    | lон = −1 mA               | V <sub>DD</sub> - 1.0 |      |                 | V    |
| Output voltage, low            | Vol             | Vol                    | IoL = 1.6 mA              |                       |      | 0.4             | V    |
| Input leakage current          | lu              | lu                     | $0 \le V_{IN} \le V_{DD}$ | -10                   |      | +10             | μΑ   |
| VPP supply voltage             | V <sub>PP</sub> | V <sub>PP</sub>        |                           | 12.2                  | 12.5 | 12.8            | V    |
| V <sub>DD</sub> supply voltage | V <sub>DD</sub> | Vcc                    |                           | 6.25                  | 6.5  | 6.75            | V    |
| VPP supply current             | Ірр             | IPP                    | PGM = VIL                 |                       |      | 50              | mA   |
| V <sub>DD</sub> supply current | Idd             | Icc                    |                           |                       |      | 50              | mA   |

## (2) **PROM Read Mode** (TA = $25 \pm 5^{\circ}$ C, VDD = $5.0 \pm 0.5$ V, VPP = VDD $\pm 0.6$ V)

| Parameter                      | Symbol           | Symbol <sup>Note</sup> | Test Conditions                                    | MIN.                  | TYP.            | MAX.      | Unit |
|--------------------------------|------------------|------------------------|--|-----------------------|-----------------|-----------|------|
| Input voltage, high            | VIH              | VIH                    |  | 0.7V <sub>DD</sub>    |                 | VDD       | V    |
| Input voltage, low             | VIL              | VIL                    |  | 0                     |                 | 0.3Vpd    | V    |
| Output voltage, high           | Vон1             | V <sub>OH1</sub>       | lон = −1 mA  | V <sub>DD</sub> - 1.0 |                 |           | V    |
|                                | V <sub>OH2</sub> | V <sub>OH2</sub>       | Іон = -100 μА                                      | V <sub>DD</sub> - 0.5 |                 |           | V    |
| Output voltage, low            | Vol              | Vol                    | IoL = 1.6 mA                                       |                       |                 | 0.4       | V    |
| Input leakage current          | Iμ               | Li                     | $0 \le V_{IN} \le V_{DD}$                          | -10                   |                 | +10       | μΑ   |
| Output leakage current         | ILO              | ILO                    | $0 \le V_{OUT} \le V_{DD}, \overline{OE} = V_{IH}$ | -10                   |                 | +10       | μΑ   |
| VPP supply voltage             | V <sub>PP</sub>  | V <sub>PP</sub>        |  | VDD - 0.6             | V <sub>DD</sub> | VDD + 0.6 | V    |
| V <sub>DD</sub> supply voltage | V <sub>DD</sub>  | Vcc                    |  | 4.5                   | 5.0             | 5.5       | V    |
| VPP supply current             | IPP              | IPP                    | VPP = VDD  |                       |                 | 100       | μΑ   |
| VDD supply current             | IDD              | ICCA1                  | CE = VIL, VIN = VIH                                |                       |                 | 50        | mA   |

Note Corresponding  $\mu PD27C1001A$  symbol.



### **AC Characteristics**

### (1) PROM Write Mode

(a) Page program mode (TA =  $25 \pm 5^{\circ}$ C, VDD =  $6.5 \pm 0.25$  V, VPP =  $12.5 \pm 0.3$  V)

| Parameter  | Symbol        | Symbol Note   | Test Conditions | MIN.  | TYP. | MAX.  | Unit |
|--|---------------|---------------|-----------------|-------|------|-------|------|
| Address setup time (to $\overline{\sf OE}\ \downarrow$ ) | tas           | tas           |                 | 2     |      |       | μs   |
| OE setup time  | toes          | toes          |                 | 2     |      |       | μs   |
| CE setup time (to OE ↓)                                  | tces          | tces          |                 | 2     |      |       | μs   |
| Input data setup time (to $\overline{OE}\ \downarrow$ )  | tos           | tos           |                 | 2     |      |       | μs   |
| Address hold time (from $\overline{OE} \uparrow$ )       | tан           | tан           |                 | 2     |      |       | μs   |
|  | <b>t</b> ahl  | tahl          |                 | 2     |      |       | μs   |
|  | tahv          | tahv          |                 | 0     |      |       | μs   |
| Input data hold time (from OE ↑)                         | tон           | tон           |                 | 2     |      |       | μs   |
| $\overline{OE} \uparrow \to Data$ output float           | tor           | tof           |                 | 0     |      | 250   | ns   |
| delay time   |               |               |                 |       |      |       |      |
| $V_{PP}$ setup time (to $\overline{OE} \downarrow$ )     | tvps          | tvps          |                 | 1.0   |      |       | ms   |
| $V_{DD}$ setup time (to $\overline{OE} \downarrow$ )     | tvds          | tvcs          |                 | 1.0   |      |       | ms   |
| Program pulse width                                      | tpw           | tpw           |                 | 0.095 | 0.1  | 0.105 | ms   |
| $\overline{OE} \downarrow \to Valid$ data delay time     | toe           | toe           |                 |       |      | 1     | μs   |
| OE pulse width during data                               | tuw           | tuw           |                 | 1     |      |       | μs   |
| latching   |               |               |                 |       |      |       |      |
| PGM setup time   | <b>t</b> PGMS | <b>t</b> PGMS |                 | 2     |      |       | μs   |
| CE hold time   | tсен          | tсен          |                 | 2     |      |       | μs   |
| OE hold time   | tоен          | tоен          |                 | 2     |      |       | μs   |

## (b) Byte program mode (T<sub>A</sub> = 25 $\pm$ 5°C, V<sub>DD</sub> = 6.5 $\pm$ 0.25 V, V<sub>PP</sub> = 12.5 $\pm$ 0.3 V)

| Parameter   | Symbol | Symbol Note | Test Conditions | MIN.  | TYP. | MAX.  | Unit |
|---|--------|-------------|-----------------|-------|------|-------|------|
| Address setup time (to $\overline{PGM}\ \downarrow$ )     | tas    | tas         |                 | 2     |      |       | μs   |
| OE set time   | toes   | toes        |                 | 2     |      |       | μs   |
| CE setup time (to PGM ↓)                                  | tces   | tces        |                 | 2     |      |       | μs   |
| Input data setup time (to $\overline{PGM}\ \downarrow$ )  | tos    | tos         |                 | 2     |      |       | μs   |
| Address hold time (from OE ↑)                             | tан    | <b>t</b> AH |                 | 2     |      |       | μs   |
| Input data hold time                                      | tон    | tон         |                 | 2     |      |       | μs   |
| (from PGM ↑)  |        |             |                 |       |      |       |      |
| $\overline{OE} \uparrow \to Data$ output float            | tor    | tor         |                 | 0     |      | 250   | ns   |
| delay time  |        |             |                 |       |      |       |      |
| $V_{PP}$ setup time (to $\overline{PGM} \downarrow$ )     | tvps   | tvps        |                 | 1.0   |      |       | ms   |
| V <sub>DD</sub> setup time (to $\overline{\text{PGM}}$ ↓) | tvds   | tvcs        |                 | 1.0   |      |       | ms   |
| Program pulse width                                       | tpw    | tpw         |                 | 0.095 | 0.1  | 0.105 | ms   |
| $\overline{OE} \downarrow \to Valid$ data delay time      | toe    | toe         |                 |       |      | 1     | μs   |
| OE hold time  | tоен   | _           |                 | 2     |      |       | μs   |

Note Corresponding  $\mu PD27C1001A$  symbol.



# (2) **PROM Read Mode** $(T_A = 25 \pm 5^{\circ}C, V_{DD} = 5.0 \pm 0.5 \text{ V}, V_{PP} = V_{DD} \pm 0.6 \text{ V})$

| Parameter   | Symbol | Symbol Note | Test Conditions                          | MIN. | TYP. | MAX. | Unit |
|---|--------|-------------|--|------|------|------|------|
| Address → Data output                                 | tacc   | tacc        | $\overline{CE} = \overline{OE} = V_{IL}$ |      |      | 800  | ns   |
| delay time  |        |             |  |      |      |      |      |
| $\overline{CE} \downarrow \to Data$ output delay time | tce    | tce         | OE = VIL                                 |      |      | 800  | ns   |
| $\overline{OE} \downarrow \to Data$ output delay time | toe    | toe         | CE = VIL                                 |      |      | 200  | ns   |
| $\overline{OE} \uparrow \to Data$ output float        | tor    | tor         | CE = VIL                                 | 0    |      | 60   | ns   |
| delay time  |        |             |  |      |      |      |      |
| Address → Data hold time                              | tон    | tон         | CE = OE = VIL                            | 0    |      |      | ns   |

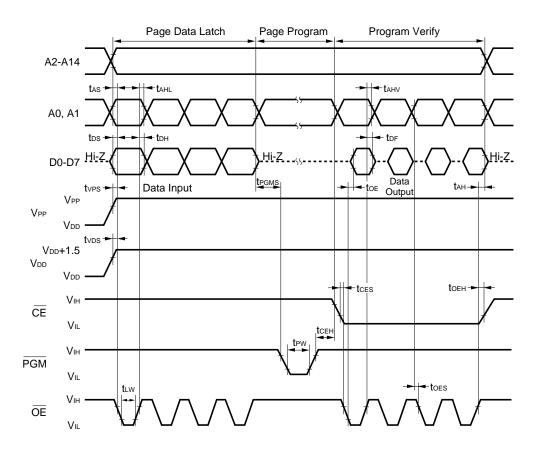
Note Corresponding  $\mu PD27C1001A$  symbol.

# (3) PROM Programming Mode $(T_A = 25^{\circ}C, V_{SS} = 0 \text{ V})$

| Parameter             | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------|--------|-----------------|------|------|------|------|
| PROM programming mode | tsma   |                 | 10   |      |      | μs   |
| setup time            |        |                 |      |      |      |      |

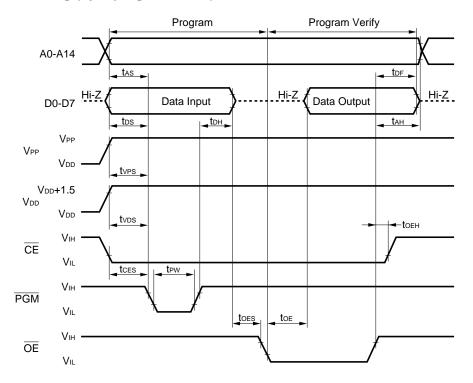


# PROM Write Mode Timing (page program mode)





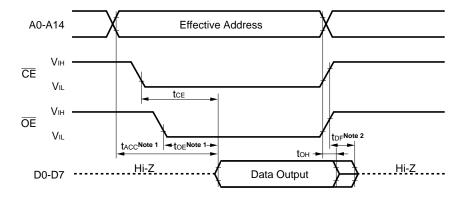
### PROM Write Mode Timing (byte program mode)



Cautions 1. VDD should be applied before VPP, and removed after VPP.

- 2. VPP must not exceed +13.5 V including overshoot.
- 3. Reliability may be adversely affected if removal/reinsertion is performed while + 12.5 V is being applied to VPP.

### **PROM Read Mode Timing**

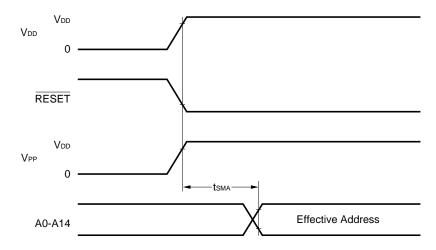


Notes 1. If you want to read within the range of tacc, make the  $\overline{\text{OE}}$  input delay time from the fall of  $\overline{\text{CE}}$  a maximum of tacctoe.

**2.** top is the time from when either  $\overline{OE}$  or  $\overline{CE}$  first reaches ViH.



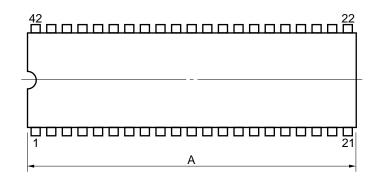
# **PROM Programming Mode Setting Timing**

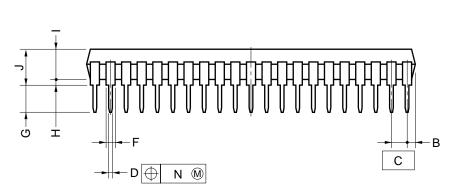


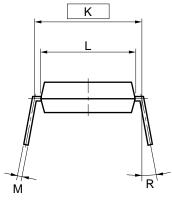


#### 9. PACKAGE DRAWINGS

# 42PIN PLASTIC SHRINK DIP (600 mil)







#### NOTES

- 1) Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

| ITEM | MILLIMETERS                    | INCHES       |
|------|--------------------------------|--------------|
| Α    | 39.13 MAX.                     | 1.541 MAX.   |
| В    | 1.78 MAX.                      | 0.070 MAX.   |
| С    | 1.778 (T.P.)                   | 0.070 (T.P.) |
| D    | 0.50±0.10                      | 0.020+0.004  |
| F    | 0.9 MIN.                       | 0.035 MIN.   |
| G    | 3.2±0.3                        | 0.126±0.012  |
| Н    | 0.51 MIN.                      | 0.020 MIN.   |
| I    | 4.31 MAX.                      | 0.170 MAX.   |
| J    | 5.08 MAX.                      | 0.200 MAX.   |
| K    | 15.24 (T.P.)                   | 0.600 (T.P.) |
| L    | 13.2                           | 0.520        |
| М    | 0.25 <sup>+0.10</sup><br>-0.05 | 0.010+0.004  |
| N    | 0.17                           | 0.007        |
| R    | 0~15°                          | 0~15°        |
|      |                                | 7100 -0 0001 |

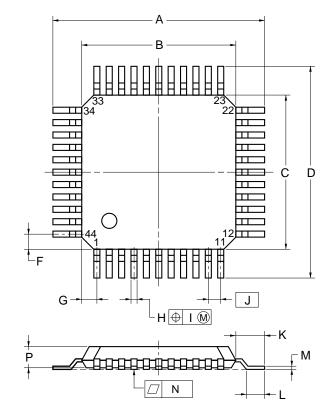
P42C-70-600A-1

Remark The shape and material of ES versions are the same as those of mass-produced versions.

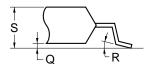


 $\mu \textbf{PD78P083GB-3B4}$ 

# 44 PIN PLASTIC QFP (□10)



detail of lead end



#### NOTE

Each lead centerline is located within 0.15 mm (0.006 inch) of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS            | INCHES                                    |
|------|------------------------|---|
| Α    | 13.6±0.4               | $0.535^{+0.017}_{-0.016}$                 |
| В    | 10.0±0.2               | $0.394^{+0.008}_{-0.009}$                 |
| С    | 10.0±0.2               | $0.394^{+0.008}_{-0.009}$                 |
| D    | 13.6±0.4               | 0.535 <sup>+0.017</sup> <sub>-0.016</sub> |
| F    | 1.0                    | 0.039                                     |
| G    | 1.0                    | 0.039                                     |
| Н    | 0.35±0.10              | 0.014+0.004                               |
| ı    | 0.15                   | 0.006                                     |
| J    | 0.8 (T.P.)             | 0.031 (T.P)                               |
| K    | 1.8±0.2                | 0.071+0.008                               |
| L    | 0.8±0.2                | 0.031+0.009                               |
| М    | $0.15^{+0.10}_{-0.05}$ | $0.006^{+0.004}_{-0.003}$                 |
| N    | 0.10                   | 0.004                                     |
| P    | 2.7                    | 0.106                                     |
| Q    | 0.1±0.1                | 0.004±0.004                               |
| R    | 5°±5°                  | 5°±5°                                     |
| S    | 3.0 MAX.               | 0.119 MAX.                                |

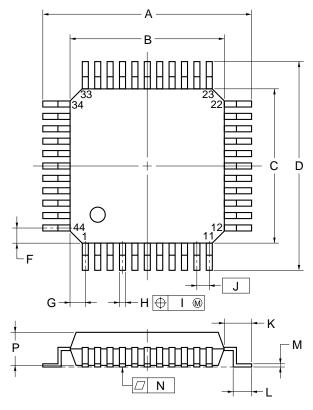
P44GB-80-3B4-3

Remark The shape and material of ES versions are the same as those of mass-produced versions.

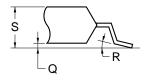


 $\mu \textbf{PD78P083GB-3BS-MTX}$ 

# 44 PIN PLASTIC QFP (□10)



detail of lead end



## NOTE

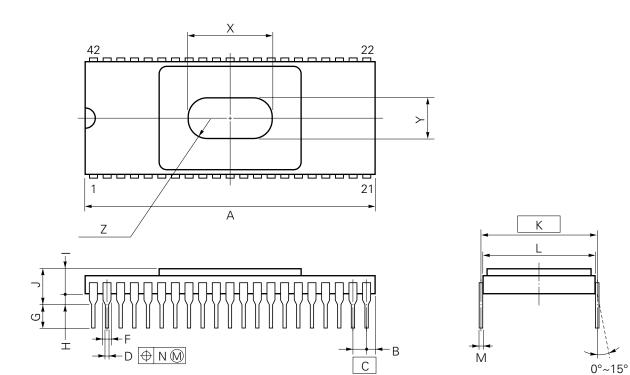
Each lead centerline is located within 0.16 mm (0.007 inch) of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS      | INCHES                    |
|------|------------------|---------------------------|
| Α    | 13.2±0.2         | $0.520^{+0.008}_{-0.009}$ |
| В    | 10.0±0.2         | 0.394+0.008               |
| С    | 10.0±0.2         | 0.394+0.008               |
| D    | 13.2±0.2         | 0.520+0.008               |
| F    | 1.0              | 0.039                     |
| G    | 1.0              | 0.039                     |
| Н    | 0.37 +0.08 -0.07 | 0.015+0.003               |
| I    | 0.16             | 0.007                     |
| J    | 0.8 (T.P.)       | 0.031 (T.P.)              |
| K    | 1.6±0.2          | 0.063±0.008               |
| L    | 0.8±0.2          | 0.031 +0.009 -0.008       |
| М    | 0.17 +0.06 -0.05 | 0.007 +0.002 -0.003       |
| N    | 0.10             | 0.004                     |
| Р    | 2.7              | 0.106                     |
| Q    | 0.125±0.075      | 0.005±0.003               |
| R    | 3°+7°<br>-3°     | 3°+7°                     |
| S    | 3.0 MAX.         | 0.119 MAX.                |
|      |                  | S44GB-80-3BS              |

**Remark** The shape and material of ES versions are the same as those of mass-produced versions.



#### 42PIN CERAMIC SHRINK DIP (WINDOW) (600 mil)



#### **NOTES**

- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

**ITEM MILLIMETERS INCHES** Α 38.25 MAX. 1.506 MAX. В 1.345 MAX. 0.053 MAX. С 1.778 (T.P.) 0.07 (T.P.) D  $0.46 \pm 0.05$ 0.018±0.002 F 0.85 MIN. 0.033 MIN. G  $3.5 \pm 0.3$ 0.138±0.012 Н 1.02 MIN. 0.040 MIN. 3.026 0.119 J 5.282 MAX. 0.208 MAX. Κ 15.24 (T.P.) 0.600 (T.P.) L 0.590 14.99  $0.010^{+0.002}_{-0.003}$ Μ  $0.25 \pm 0.05$ Ν 0.25 0.01 Χ 12.0 0.472 Υ 6.0 0.236 4-R3.0 4-R0.118 Ζ

P42DW-70-600A



#### 10. RECOMMENDED SOLDERING CONDITIONS

\*

It is recommended that the  $\mu PD78P083$  be soldered under the following conditions.

For details on the recommended soldering conditions, refer to information document "Semiconductor Device Mounting Technology Manual" (C10535E).

For soldering methods and conditions other than those recommended, please contact your NEC sales representative.

Table 10-1. Soldering Conditions for Surface Mount Types

 $\mu PD78P083GB\text{-}3B4$  : 44-pin plastic QFP (10 x 10 mm)  $\mu PD78P083GB\text{-}3BS\text{-}MTX$  : 44-pin plastic QFP (10 x 10 mm)

| Soldering Method    | Soldering Conditions  | Symbol    |
|---------------------|---|-----------|
| Infrared ray reflow | Package peak temperature: 235°C, Reflow time: 30 seconds or         | IR35-00-2 |
|                     | less (at 210°C or higher), Number of reflow processes: 2 or less    |           |
|                     | < Cautions >  |           |
|                     | (1) Wait for the device temperature to return to normal after the   |           |
|                     | first reflow before starting the second reflow.                     |           |
|                     | (2) Do not perform flux cleaning with water after the first reflow. |           |
| VPS                 | Package peak temperature: 215°C, Reflow time: 40 seconds or         | VP15-00-2 |
|                     | less (at 200°C or higher), Number of reflow processes: 2 or less    |           |
|                     | < Cautions >  |           |
|                     | (1) Wait for the device temperature to return to normal after the   |           |
|                     | first reflow before starting the second reflow.                     |           |
|                     | (2) Do not perform flux cleaning with water after the first reflow. |           |
| Wave soldering      | Solder temperature: 260°C or below, Flow time: 10 seconds or        | WS60-00-1 |
|                     | less, Number of flow processes: 1,                                  |           |
|                     | Preheating temperature: 120°C max. (package surface                 |           |
|                     | temperature)  |           |
| Partial heating     | Pin temperature: 300°C or below,                                    | _         |
|                     | Flow time: 3 seconds or less (per pin row)                          |           |

Caution Do not use different soldering methods together (except for partial heating method).

Table 10-2. Soldering Condition for Hole-Through Types

 $\mu$ PD78P083CU : 42-pin plastic shrink DIP (600 mil)

μPD78P083DU: 42-pin ceramic shrink DIP (with window) (600 mil)

| Soldering Method           | Soldering Conditions  |
|----------------------------|---|
| Wave Soldering (only pins) | Solder temperature: 260°C or below, Flow time: 10 seconds or less       |
| Partial heating            | Pin temperature: 300°C or below, Flow time: 3 seconds or less (per pin) |

Caution Apply wave soldering only to the pins and be careful so as not to bring solder into direct contact with the package.



#### APPENDIX A. DEVELOPMENT TOOLS \*

The following development tools are available to support development of systems using the  $\mu$ PD78P083.

#### **Language Processing Software**

| RA78K/0 Notes 1, 2, 3, 4   | Assembler package common to the 78K/0 series              |
|----------------------------|---|
| CC78K/0 Notes 1, 2, 3, 4   | C compiler package common to the 78K/0 series             |
| DF78083 Notes 1, 2, 3, 4   | Device file used for the μPD78083 subseries               |
| CC78K/0-L Notes 1, 2, 3, 4 | C compiler library source file common to the 78K/0 series |

#### **PROM Writing Tools**

| PG-1500                       | PROM programmer                             |
|-------------------------------|---|
| PA-78P083CU                   | Programmer adapter connected to the PG-1500 |
| PA-78P083GB                   |   |
| PG-1500 Controller Notes 1, 2 | Control program for the PG-1500             |

#### **Debugging Tools**

| IE-78000-R                  | In-circuit emulator common to the 78K/0 series                            |
|-----------------------------|---|
| IE-78000-R-A Note 8         | In-circuit emulator common to the 78K/0 series (for integrated debugger)  |
| IE-78000-R-BK               | Break board common to the 78K/0 series                                    |
| IE-78078-R-EM               | Emulation board common to the μPD78078 subseries                          |
| EP-78083CU-R                | Emulation probe for the μPD78083 subseries                                |
| EP-78083GB-R                |   |
| EV-9200G-44                 | Socket mounted on the target system board prepared for 44-pin plastic QFP |
| SM78K0 Notes 5, 6, 7        | System simulator common to the 78K/0 series                               |
| ID78K0 Notes 4, 5, 6, 7, 8  | Integrated debugger for IE-78000-R-A                                      |
| SD78K/0 Notes 1, 2          | Screen debugger for the IE-78000-R  |
| DF78083 Notes 1, 2, 5, 6, 7 | Device file used for the μPD78083 subseries                               |

#### Notes 1. Based on PC-9800 series (MS-DOS™)

- 2. Based on IBM PC/AT™ and its compatibles (PC DOS™/IBM DOS™/MS-DOS)
- 3. Based on HP9000 series 300™ (HP-UX™)
- 4. Based on HP9000 series 700™ (HP-UX), SPARCstation™ (SunOS™), and EWS4800 series (EWS-UX/V)
- 5. Based on PC-9800 series (MS-DOS + Windows™)
- **6.** IBM PC/AT and its compatibles (PC DOS/IBM DOS/MS-DOS + Windows)
- **7.** Based on NEWS<sup>™</sup> (NEWS-OS<sup>™</sup>)
- 8. Under development

- Remarks 1. Please refer to the 78K/0 Series Selection Guide (U11126E) for information on the third party development
  - 2. Use the RA78K/0, CC78K/0, SM78K0, ID78K0, and SD78K/0 in combination with the DF78083.



### **Fuzzy Inference Development Support System**

| FE9000 Note 1/FE9200 Note 2 | Fuzzy knowledge data creation tool |
|-----------------------------|------------------------------------|
| FT9080 Note 1/FT9085 Note 3 | Translator                         |
| FI78K0 Notes 1, 3           | Fuzzy inference module             |
| FD78K0 Notes 1, 3           | Fuzzy inference debugger           |

#### Notes 1. Based on PC-9800 series (MS-DOS)

- 2. Based on IBM PC/AT and its compatibles (PC DOS/IBM DOS/MS-DOS+Windows)
- 3. Based on IBM PC/AT and its compatibles (PC DOS/IBM DOS/MS-DOS)

**Remark** Please refer to the **78K/0 Series Selection Guide (U11126E)** for information on the third party development tools.



## \* APPENDIX B. RELATED DOCUMENTS

#### **Documents Related to Devices**

| Document Name                                      |             | Document No. |          |
|--|-------------|--------------|----------|
|  |             | Japanese     | English  |
| μPD78083 Subseries User's Manual                   |             | IEU-886      | IEU-1407 |
| 78K/0 Series User's Manual—Instructions            |             | IEU-849      | IEU-1372 |
| 78K/0 Series Instruction Table                     |             | U10903J      | _        |
| 78K/0 Series Instruction Set                       |             | U10904J      | _        |
| μPD78083 Subseries Special Function Register Table |             | IEM-5599     | _        |
| 78K/0 Series Application Note                      | Basic (III) | IEA-767      | U10182E  |

### **Documents Related to Development Tools (User's Manual)**

| Document Name                                    |                    | Document No. |          |
|--|--------------------|--------------|----------|
|  |                    | Japanese     | English  |
| RA78K Series Assembler Package                   | Operation          | EEU-809      | EEU-1399 |
|  | Language           | EEU-815      | EEU-1404 |
| RA78K Series Structured Assembler Preprocessor   |                    | EEU-817      | EEU-1402 |
| CC78K Series C Compiler                          | Operation          | EEU-656      | EEU-1280 |
|  | Language           | EEU-655      | EEU-1284 |
| CC78K/0 C Compiler Application Note              | Programming        | EEA-618      | EEA-1208 |
|  | know-how           |              |          |
| CC78K Series Library Source File                 |                    | EEU-777      | _        |
| PG-1500 PROM Programmer                          |                    | EEU-651      | EEU-1335 |
| PG-1500 Controller PC-9800 Series (MS-DOS) Based |                    | EEU-704      | EEU-1291 |
| PG-1500 Controller IBM PC Series (PC DOS) Based  |                    | EEU-5008     | U10540E  |
| IE-78000-R                                       |                    | EEU-810      | EEU-1398 |
| IE-78000-R-A                                     |                    | U10057J      | U10057E  |
| IE-78000-R-BK                                    |                    | EEU-867      | EEU-1427 |
| IE-78078-R-EM                                    |                    | U10775J      | EEU-1504 |
| EP-78083   |                    | EEU-5003     | EEU-1529 |
| SM78K0 System Simulator                          | Reference          | EEU-5002     | U10181E  |
| SM78K Series System Simulator                    | Third party's user | U10092J      | U10092E  |
|  | open interface     |              |          |
|  | specifications     |              |          |
| SD78K/0 Screen Debugger                          | Introduction       | EEU-852      | _        |
| PC-9800 Series (MS-DOS) Based                    | Reference          | U10952J      | _        |
| SD78K/0 Screen Debugger                          | Introduction       | EEU-5024     | EEU-1414 |
| IBM PC/AT (PC DOS) Based                         | Reference          | EEU-993      | EEU-1413 |

Caution The contents of the documents listed above are subject to change without prior notice. Make sure to use the latest edition when starting design.



## **Documents Related to Embedded Software (User's Manual)**

| Document Name  |                 | Document No. |          |
|--|-----------------|--------------|----------|
|  |                 | Japanese     | English  |
| 78K/0 Series OS MX78K0   | Basic           | EEU-5010     | _        |
| Fuzzy Knowledge Data Creation Tool   |                 | EEU-829      | EEU-1438 |
| 78K/0, 78K/II, and 87AD Series Fuzzy Inference Development Support System Translator |                 | EEU-862      | EEU-1444 |
| 78K/0 Series Fuzzy Inference Development Support System Fuzzy Inference Module       |                 | EEU-858      | EEU-1441 |
| 78K/0 Series Fuzzy Inference Development Support System Fuzzy Inf                    | erence Debugger | EEU-921      | EEU-1458 |

#### **Other Documents**

| Document Name  | Document No. |          |
|--|--------------|----------|
|  | Japanese     | English  |
| Semiconductor Device Package Manual                            | IEI-635      | IEI-1213 |
| Semiconductor Device Mounting Technology Manual                | C10535J      | C10535E  |
| Quality Grades on NEC Semiconductor Devices                    | IEI-620      | IEI-1209 |
| NEC Semiconductor Device Reliability/Quality Control System    | C10983J      | C10983E  |
| Electrostatic Discharge (ESD) Test                             | MEM-539      | IEI-1201 |
| Guide to Quality Assurance for Semicoductor Devices            | MEI-603      | MEI-1202 |
| Microcontroller-Related Product Guide - Third Party Products - | MEI-604      | _        |

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NEC  $\mu$ PD78P083

[MEMO]

## **NOTES FOR CMOS DEVICES -**

# 1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

# (2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

# (3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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